

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L8	20214	(cv c-v (capacitance adj voltage))	USPAT	2005/05/12 10:18
2	BRS	L9	318	8 and (carrier carriers charge electron electrons) near3 (profiling profile distribution distribute)	USPAT	2005/05/12 10:33
3	BRS	L10	1	9 and (liquid water) adj electrode	USPAT	2005/05/12 10:20
4	BRS	L11	12	8 and (liquid water) adj electrode	USPAT	2005/05/12 10:20
5	BRS	L12	10	11 and (semiconductor indium gallium layer layers)	USPAT	2005/05/12 10:57
6	BRS	L13	689	8 and (((carrier carriers charge electron electrons) near3 (profiling profile distribution distribute concentration)) (carrier adj concentration adj profiling))	USPAT	2005/05/12 10:35
7	BRS	L14	1	13 and (liquid water) adj electrode	USPAT	2005/05/12 10:36
8	BRS	L15	59	13 and (edta)	USPAT	2005/05/12 10:56
9	BRS	L17	9	13 and (edta near3 solution)	USPAT	2005/05/12 10:57
10	BRS	L18	6	17 and (semiconductor indium gallium layer layers)	USPAT	2005/05/12 10:59
11	BRS	L19	0	17 and (semiconductor indium gallium)	USPAT	2005/05/12 10:59